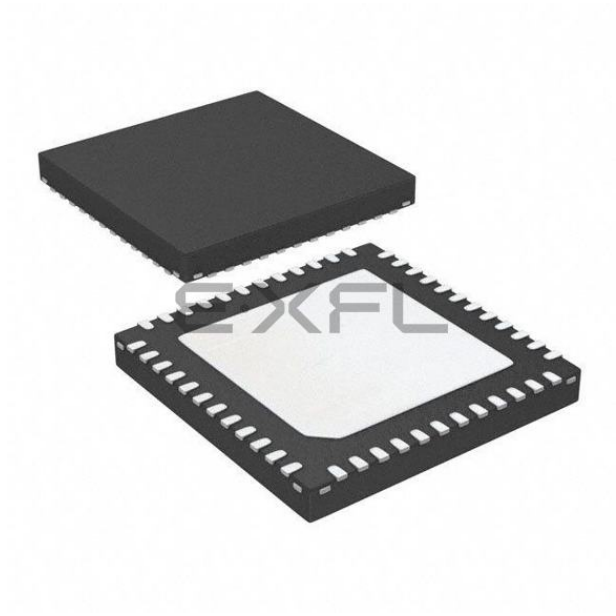

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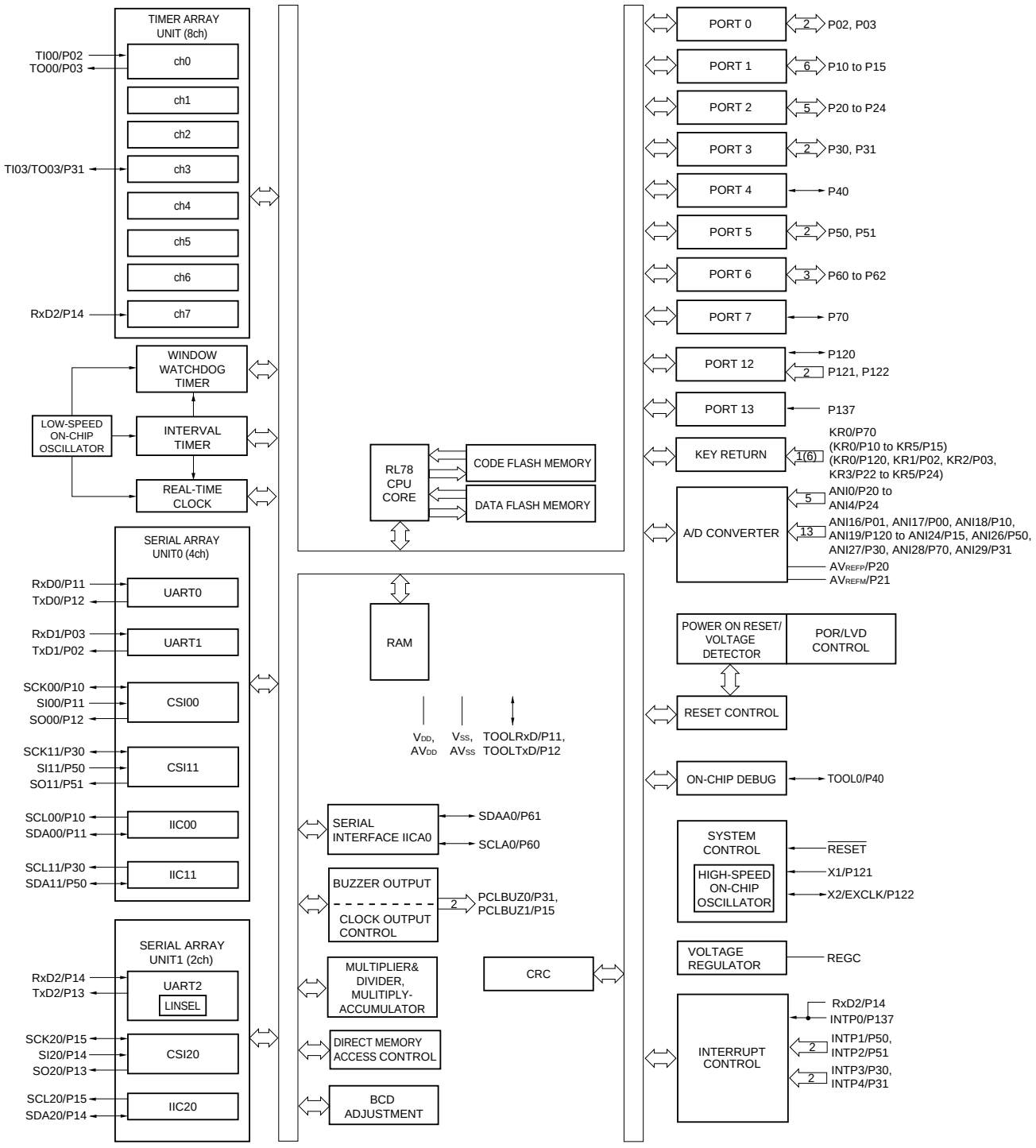
What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

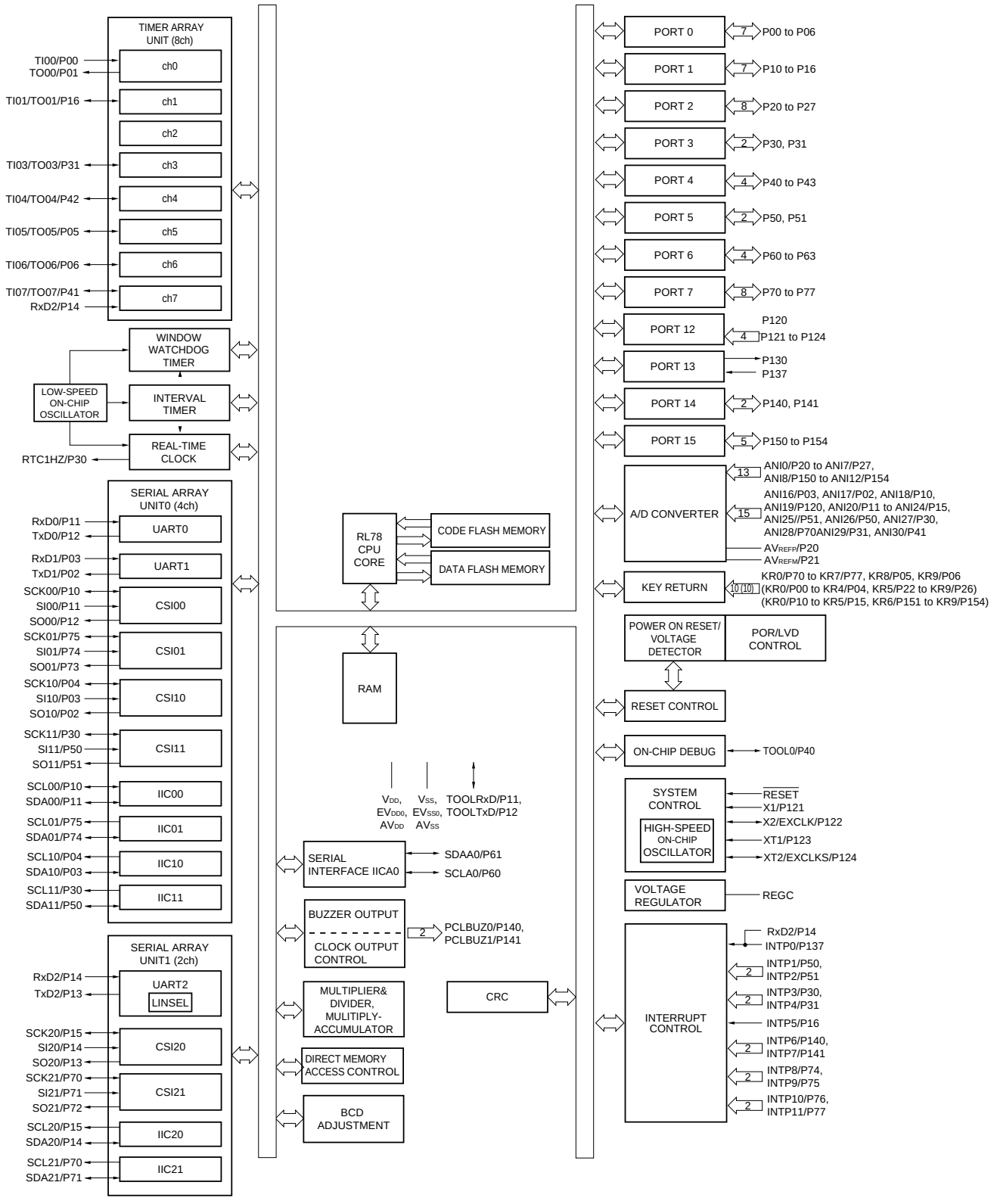
Details	
Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I²C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	32
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 3.6V
Data Converters	A/D 24x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-WFQFN Exposed Pad
Supplier Device Package	48-HWQFN (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10egaana-u0

<R> 1.5.2 32-pin products



Remark Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR).

1.5.4 64-pin products



Remark Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR).

(2/2)

Item		25-pin R5F10E8x	32-pin R5F10EBx	48-pin R5F10EGx	64-pin R5F10ELx
Clock output/buzzer output		1	2	2	2
		• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f_{MAIN} = 20 MHz operation)		• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f_{MAIN} = 20 MHz operation) • 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: f_{SUB} = 32.768 kHz operation)	
8/12-bit resolution A/D converter		13 channels	18 channels	24 channels	28 channels
Serial interface		[25-pin products] • CSI: 1 channel/simplified I^2C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I^2C: 1 channel/UART: 1 channel [32-pin products] • CSI: 1 channel/simplified I^2C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I^2C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I^2C: 1 channel/UART (UART supporting LIN-bus): 1 channel [48-pin products] • CSI: 2 channels/simplified I^2C: 2 channels/UART: 1 channel • CSI: 1 channel/simplified I^2C: 1 channel/UART: 1 channel • CSI: 2 channels/simplified I^2C: 2 channels/UART (UART supporting LIN-bus): 1 channel [64-pin products] • CSI: 2 channels/simplified I^2C: 2 channels/UART: 1 channel • CSI: 2 channels/simplified I^2C: 2 channels/UART: 1 channel • CSI: 2 channels/simplified I^2C: 2 channels/UART (UART supporting LIN-bus): 1 channel			
	I^2C bus	1 channel	1 channel	1 channel	1 channel
Multiplier and divider/multiply-accumulator		• 16 bits × 16 bits = 32 bits (Unsigned or signed) • 32 bits ÷ 32 bits = 32 bits (Unsigned) • 16 bits × 16 bits + 32 bits = 32 bits (Unsigned or signed)			
DMA controller		2 channels			
Vectored interrupt sources	Internal	24	27	27	27
	External	6	6	10	13
Key interrupt		0 ch (4 ch)Note 1	1 ch (6 ch)Note 1	6 ch	10 ch
Reset		• Reset by $\overline{\text{RESET}}$ pin • Internal reset by watchdog timer • Internal reset by power-on-reset • Internal reset by voltage detector • Internal reset by illegal instruction executionNote 2 • Internal reset by RAM parity error • Internal reset by illegal-memory access			
Power-on-reset circuit		• Power-on-reset: 1.51 V (TYP.) • Power-down-reset: 1.50 V (TYP.)			
Voltage detector		• Rising edge : 1.67 V to 3.14 V (12 stages) • Falling edge : 1.63 V to 3.06 V (12 stages)			
On-chip debug function		Provided			
Power supply voltage		V_{DD} = 1.6 to 3.6 V			
Operating ambient temperature		T_A = −40 to +85°C (A: Consumer application), T_A = −40 to +105°C (G: Industrial application)			

Notes 1. Can be used by the Peripheral I/O redirection register (PIOR).

2. The illegal instruction is generated when instruction code FFH is executed.
Reset by the illegal instruction execution not issued by emulation with the in-circuit emulator or on-chip debug emulator.

Absolute Maximum Ratings (T_A = 25°C) (2/2)

Parameter	Symbols	Conditions		Ratings	Unit
Output current, high	I_{OH1}	Per pin	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P70 to P77, P120, P130, P140, P141	–40	mA
		Total of all pins –170 mA	P00 to P04, P40 to P43, P120, P130, P140, P141	–70	mA
			P05, P06, P10 to P16, P30, P31, P50, P51, P70 to P77,	–100	mA
	I_{OH2}	Per pin	P20 to P27, P150 to P154	–0.1	mA
		Total of all pins		–1.3	mA
Output current, low	I_{OL1}	Per pin	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P60 to P63, P70 to P77, P120, P130, P140, P141	40	mA
		Total of all pins 170 mA	P00 to P04, P40 to P43, P120, P130, P140, P141	70	mA
			P05, P06, P10 to P16, P30, P31, P50, P51, P60 to P63, P70 to P77	100	mA
	I_{OL2}	Per pin	P20 to P27, P150 to P154	0.4	mA
		Total of all pins		6.4	mA
Operating ambient temperature	T_A	In normal operation mode		–40 to +85	°C
		In flash memory programming mode			
Storage temperature	T_{stg}			–65 to +150	°C

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

2.3.2 Supply current characteristics

(T_A = –40 to +85°C, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V) **(1/3)**

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current[Note 1]	I_{DD1}	Operating mode	HS (high-speed main) mode[Note 5]	f_{IH} = 32 MHz[Note 3]	Basic operation	V_{DD} = 3.0 V		2.1		mA
					Normal operation	V_{DD} = 3.0 V		4.6	7.0	mA
				f_{IH} = 24 MHz[Note 3]	Normal operation	V_{DD} = 3.0 V		3.7	5.5	mA
				f_{IH} = 16 MHz[Note 3]	Normal operation	V_{DD} = 3.0 V		2.7	4.0	mA
			LS (low-speed main) mode[Note 5]	f_{IH} = 8 MHz[Note 3]	Normal operation	V_{DD} = 3.0 V		1.2	1.8	mA
						V_{DD} = 2.0 V		1.2	1.8	
			LV (Low-voltage main) mode[Note 5]	f_{IH} = 4 MHz[Note 3]	Normal operation	V_{DD} = 3.0 V		1.2	1.7	mA
						V_{DD} = 2.0 V		1.2	1.7	
			HS (high-speed main) mode[Note 5]	f_{MX} = 20 MHz[Note 2], V_{DD} = 3.0 V	Normal operation	Square wave input		3.0	4.6	mA
						Resonator connection		3.2	4.8	
				f_{MX} = 10 MHz[Note 2], V_{DD} = 3.0 V	Normal operation	Square wave input		1.9	2.7	mA
						Resonator connection		1.9	2.7	
			LS (low-speed main) mode[Note 5]	f_{MX} = 8 MHz[Note 2], V_{DD} = 3.0 V	Normal operation	Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	
				f_{MX} = 8 MHz[Note 2], V_{DD} = 2.0 V	Normal operation	Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	
			Subsystem clock mode	f_{SUB} = 32.768 kHz[Note 4] T_A = –40°C	Normal operation	Square wave input		4.1	4.9	μA
						Resonator connection		4.2	5.0	
				f_{SUB} = 32.768 kHz[Note 4] T_A = +25°C	Normal operation	Square wave input		4.2	4.9	μA
						Resonator connection		4.3	5.0	
				f_{SUB} = 32.768 kHz[Note 4] T_A = +50°C	Normal operation	Square wave input		4.3	5.5	μA
						Resonator connection		4.4	5.6	
				f_{SUB} = 32.768 kHz[Note 4] T_A = +70°C	Normal operation	Square wave input		4.5	6.3	μA
						Resonator connection		4.6	6.4	
				f_{SUB} = 32.768 kHz[Note 4] T_A = +85°C	Normal operation	Square wave input		4.8	7.7	μA
						Resonator connection		4.9	7.8	

(**Notes** and **Remarks** are listed on the next page.)

Notes 1. Total current flowing into V_{DD} and EV_{DD0}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD}, EV_{DD0} or V_{SS}, EV_{SS0}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, on-chip pull-up/pull-down resistors, and data flash rewriting.

2. During HALT instruction execution by flash memory.

3. When high-speed on-chip oscillator and subsystem clock are stopped.

4. When high-speed system clock and subsystem clock are stopped.

5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). Including the current flowing into the RTC. However, not including the current flowing into the 12-bit interval timer, and watchdog timer.

6. When subsystem clock is stopped. Not including the current flowing into the RTC, 12-bit interval timer, watchdog timer.

7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: 2.7 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 32 MHz
2.4 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 16 MHz
LS (low-speed main) mode: 1.8 V ≤ V_{DD} < 3.6 V@1 MHz to 8 MHz
LV (low-voltage main) mode: 1.6 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 4 MHz

8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

Remarks 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2. f_{IH}: High-speed on-chip oscillator clock frequency

3. f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)

4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T_A = 25°C

<R> **(T_A = –40 to +85°C, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)** **(3/3)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I_{FIL} Note 1				0.20		μA
RTC operating current	I_{RTC} Notes 1, 2, 3				0.02		μA
12-bit interval timer operating current	I_{IT} Notes 1, 2, 4				0.02		μA
Watchdog timer operating current	I_{WDT} Notes 1, 2, 5	f_{IL} = 15 kHz			0.22		μA
A/D converter operating current	I_{ADC} Notes 6, 7	AV_{DD} = 3.0 V, When conversion at maximum speed			420	720	μA
$AV_{REF(+)}$ current	I_{AVREF} Note 8	AV_{DD} = 3.0 V, ADREFP1 = 0, ADREFP0 = 0 Note 7			14.0	25.0	μA
		AV_{REFP} = 3.0 V, ADREFP1 = 0, ADREFP0 = 1 Note 10			14.0	25.0	μA
		ADREFP1 = 1, ADREFP0 = 0 Note 1			14.0	25.0	μA
A/D converter reference voltage current	I_{ADREF} Notes 1, 9	V_{DD} = 3.0 V			75.0		μA
Temperature sensor operating current	I_{TMP} Note 1	V_{DD} = 3.0 V			75.0		μA
LVD operating current	I_{LVD} Notes 1, 11				0.08		μA
BGO operating current	I_{BGO} Notes 1, 12				2.5	12.2	mA
Self-programming operating current	I_{FSP} Notes 1, 13				2.5	12.2	mA
SNOOZE operating current	I_{SNOZ}	A/D converter operation (AV_{DD} = 3.0 V)	The mode is performed Notes 1, 14		0.50	0.60	mA
			During A/D conversion Note 1		0.60	0.75	mA
			During A/D conversion Note 7		420	720	μA
		CSI/UART operation Note 1			0.70	0.84	mA

(**Notes** and **Remarks** are listed on the next page.)

(5) During communication at same potential (simplified I^2C mode) (2/2)

(T_A = –40 to +85°C, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions	HS[Note 1]		LS[Note 2]		LV[Note 3]		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data hold time (transmission)	$t_{HD:DAT}$	2.7 V ≤ EV_{DD0} ≤ 3.6 V, C_b = 50 pF, R_b = 2.7 kΩ	0	305	0	305	0	305	ns
		1.8 V ≤ EV_{DD0} ≤ 3.6 V, C_b = 100 pF, R_b = 3 kΩ	0	355	0	355	0	355	ns
		1.8 V ≤ EV_{DD0} < 2.7 V, C_b = 100 pF, R_b = 5 kΩ	0	405	0	405	0	405	ns
		1.7 V ≤ EV_{DD0} ≤ 1.8 V, C_b = 100 pF, R_b = 5 kΩ	0	405	0	405	0	405	ns
		1.6 V ≤ EV_{DD0} < 1.8 V, C_b = 100 pF, R_b = 5 kΩ	–	–	0	405	0	405	ns

Notes 1. HS is condition of HS (high-speed main) mode.

2. LS is condition of LS (low-speed main) mode.

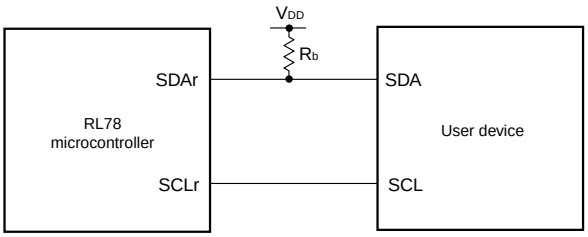
3. LV is condition of LV (low-voltage main) mode.

4. The value must also be f_{CLK}/4 or lower.

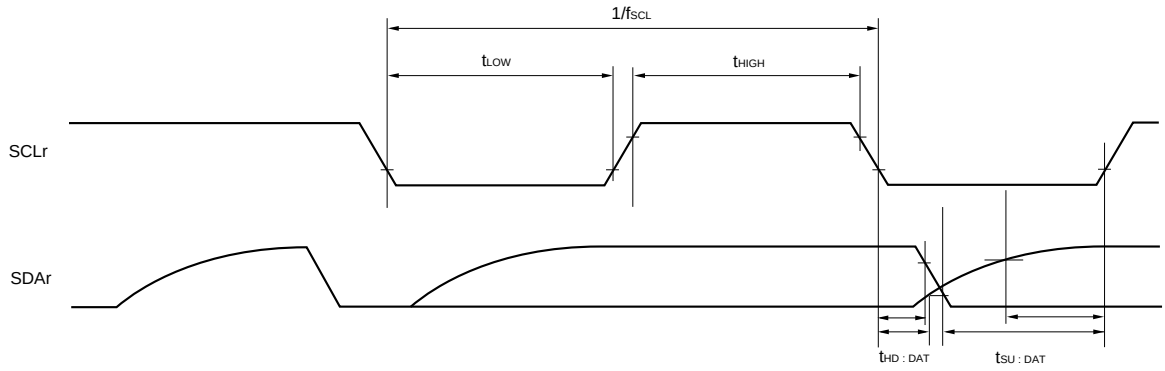
5. Set the f_{MCK} value to keep the hold time of SCLr = “L” and SCLr = “H”.

Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance (When 25- to 48-pin products)/EV_{DD} tolerance (When 64-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

Simplified I^2C mode mode connection diagram (during communication at same potential)



Simplified I^2C mode serial transfer timing (during communication at same potential)



Remarks 1. R_b[Ω]: Communication line (SDAr) pull-up resistance, C_b[F]: Communication line (SDAr, SCLr) load capacitance

2. r: IIC number (r = 00, 01, 10, 11, 20, 21), g: PIM number (g = 0, 1), h: POM number (h = 0, 1)

3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number, mn = 00 to 03, 10, 11)

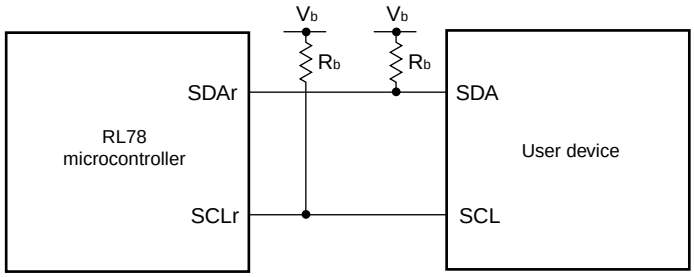
(10) Communication at different potential (1.8 V, 2.5 V) (simplified I^2C mode) (1/2)

(T_A = –40 to +85°C, 1.8 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

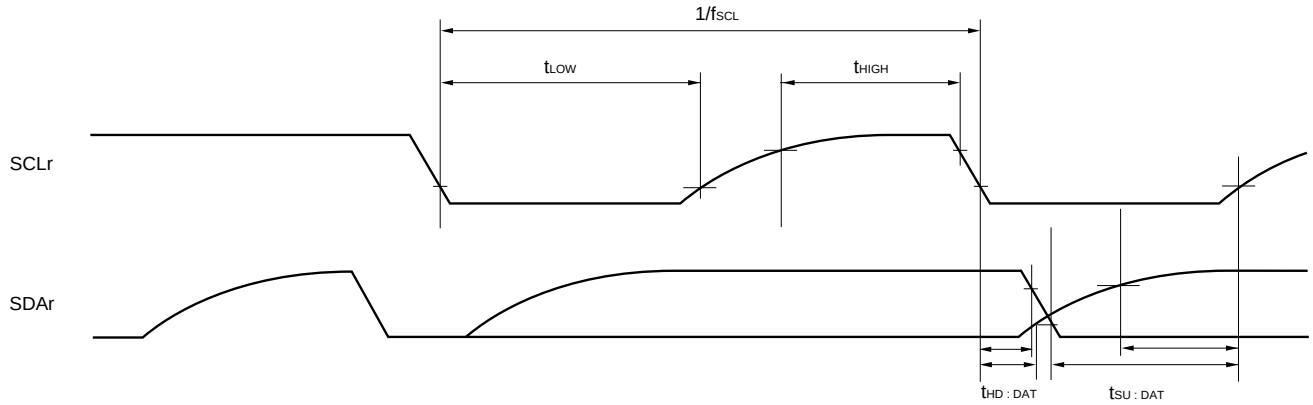
Parameter	Symbol	Conditions	HS[Note 1]		LS[Note 2]		LV[Note 3]		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	f_{SCL}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ		1000[Note 4]		300[Note 4]		300[Note 4]	kHz
		2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ		400[Note 4]		300[Note 4]		300[Note 4]	kHz
		1.8 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V[Note 5], C_b = 100 pF, R_b = 5.5 kΩ		300[Note 4]		300[Note 4]		300[Note 4]	kHz
Hold time when SCLr = “L”	t_{LOW}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	475		1550		1550		ns
		2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	1150		1550		1550		ns
		1.8 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V[Note 5], C_b = 100 pF, R_b = 5.5 kΩ	1550		1550		1550		ns
Hold time when SCLr = “H”	t_{HIGH}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	200		610		610		ns
		2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	600		610		610		ns
		1.8 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V[Note 5], C_b = 100 pF, R_b = 5.5 kΩ	610		610		610		ns

(**Notes**, **Caution** and **Remarks** are listed on the next page.)

Simplified I²C mode connection diagram (during communication at different potential)



Simplified I²C mode serial transfer timing (during communication at different potential)



Remarks 1. R_b[Ω]: Communication line (SDAr, SCLr) pull-up resistance, C_b[F]: Communication line (SDAr, SCLr) load capacitance, V_b[V]: Communication line voltage

2. r: IIC number (r = 00, 10, 20), g: PIM, POM number (g = 0, 1)

3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 02, 10)

4. IIC01, IIC11, and IIC21 cannot communicate at different potential. Use IIC00, IIC10, or IIC20 for communication at different potential.

(2) I^2C fast mode, fast mode plus

(T_A = –40 to +85°C, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions	Fast Mode[Note 7]						Fast Mode Plus[Note 8]		Unit
			HS[Note 2]		LS[Note 3]		LV[Note 4]		HS[Note 2]		
			MIN.	MAX.	MIN.	MIN.	MAX.	MIN.	MAX.	MIN.	
SCLA0 clock frequency	f_{SCL}	2.7 V ≤ EV_{DD0} ≤ 3.6 V	0	400	0	400	0	400	0	1000	kHz
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	0	400	0	400	0	400	–		
Setup time of restart condition	$t_{SU:STA}$	2.7 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		0.26		μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		–		
Hold time[Note 5]	$t_{HD:STA}$	2.7 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		0.26		μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		–		
Hold time when SCLA0 = “L”	t_{LOW}	2.7 V ≤ EV_{DD0} ≤ 3.6 V	1.3		1.3		1.3		0.5		μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	1.3		1.3		1.3		–		
Hold time when SCLA0 = “H”	t_{HIGH}	2.7 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		0.26		μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		–		
Data setup time (reception)	$t_{SU:DAT}$	2.7 V ≤ EV_{DD0} ≤ 3.6 V	100		100		100		50		ns
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	100		100		100		–		
Data hold time (transmission)[Note 6]	$t_{HD:DAT}$	2.7 V ≤ EV_{DD0} ≤ 3.6 V	0	0.9	0	0.9	0	0.9	0	450	μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	0	0.9	0	0.9	0	0.9	–		
Setup time of stop condition	$t_{SU:STO}$	2.7 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		0.26		μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	0.6		0.6		0.6		–		
Bus-free time	t_{BUF}	2.7 V ≤ EV_{DD0} ≤ 3.6 V	1.3		1.3		1.3		0.5		μs
		1.8 V ≤ EV_{DD0} ≤ 3.6 V	1.3		1.3		1.3		–		

Notes 1. In normal mode, use it with f_{CLK} ≥ 1 MHz, 1.6 V ≤ EV_{DD} ≤ 3.6 V.

2. HS is condition of HS (high-speed main) mode.

3. LS is condition of LS (low-speed main) mode.

4. LV is condition of LV (low-voltage main) mode.

5. The first clock pulse is generated after this period when the start/restart condition is detected.

6. The maximum value (MAX.) of $t_{HD:DAT}$ is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

7. In fast mode, use it with f_{CLK} ≥ 3.5 MHz, 1.8 V ≤ EV_{DD} ≤ 3.6 V.

8. In fast mode plus, use it with f_{CLK} ≥ 10 MHz, 2.7 V ≤ EV_{DD} ≤ 3.6 V.

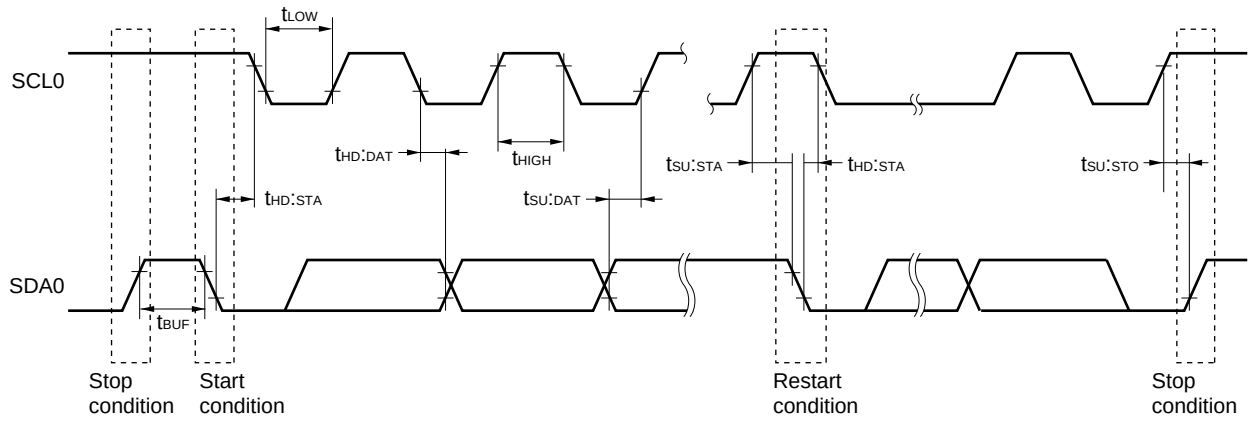
Remark The maximum value of C_b (communication line capacitance) and the value of R_b (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: C_b = 400 pF, R_b = 2.7 kΩ

Fast mode: C_b = 320 pF, R_b = 1.1 kΩ

Fast mode plus: C_b = 120 pF, R_b = 1.1 kΩ

IICA serial transfer timing



<R> **(4) When reference voltage (+) = AV_{REFP}/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (–) = AV_{REFM}/ANI1 (ADREFM = 1), target for conversion: ANI16 to ANI30, interanal reference voltage, temperature sensor output voltage**

(T_A = –40 to +85°C, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, 1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V, AV_{SS} = 0 V, Reference voltage (+) = AV_{REFP}, Reference voltage (–) = AV_{REFM} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	R_{ES}		2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	8		12	bit
			1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	8		10 Note 1	
			1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	8 Note 2			
Overall error Note 3	AINL	12-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±7.0	LSB
		10-bit resolution	1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±5.5	
		8-bit resolution	1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±3.0	
Conversion time	t_{CONV}	ADTYP = 0, 12-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	4.125			μs
		ADTYP = 0, 10-bit resolution Note 1	1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	9.5			
		ADTYP = 0, 8-bit resolution Note 2	1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	57.5			
		ADTYP = 1, 8-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	3.3125			
			1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	7.875			
			1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V	54.25			
Zero-scale error Note 3	E_{ZS}	12-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±5.0	LSB
		10-bit resolution	1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±5.0	
		8-bit resolution	1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±2.5	
Full-scale error Note 3	E_{FS}	12-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±5.0	LSB
		10-bit resolution	1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±5.0	
		8-bit resolution	1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±2.5	
Integral linearity error Note 3	ILE	12-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±3.0	LSB
		10-bit resolution	1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±2.0	
		8-bit resolution	1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±1.5	
Differential linearity error Note 3	DLE	12-bit resolution	2.4 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±2.0	LSB
		10-bit resolution	1.8 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±2.0	
		8-bit resolution	1.6 V ≤ AV_{REFP} ≤ AV_{DD} ≤ 3.6 V			±1.5	
Analog input voltage	V_{AIN}			0		AV_{REFP} and EV_{DD0}	V
		Interanal reference voltage (2.4 V ≤ V_{DD} ≤ 3.6 V, HS (high-speed main) mode)		V_{BGR} Note 4			V
		Temperature sensor output voltage (2.4 V ≤ V_{DD} ≤ 3.6 V, HS (high-speed main) mode)		V_{TMPS25} Note 4			V

Notes 1. Cannot be used for lower 2 bit of ADCR register

2. Cannot be used for lower 4 bit of ADCR register

3. Excludes quantization error (±1/2 LSB).

4. See **2.6.2 Temperature sensor, internal reference voltage output characteristics**.

2.9 Dedicated Flash Memory Programmer Communication (UART)

(T_A = –40 to +85°C, 1.8 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

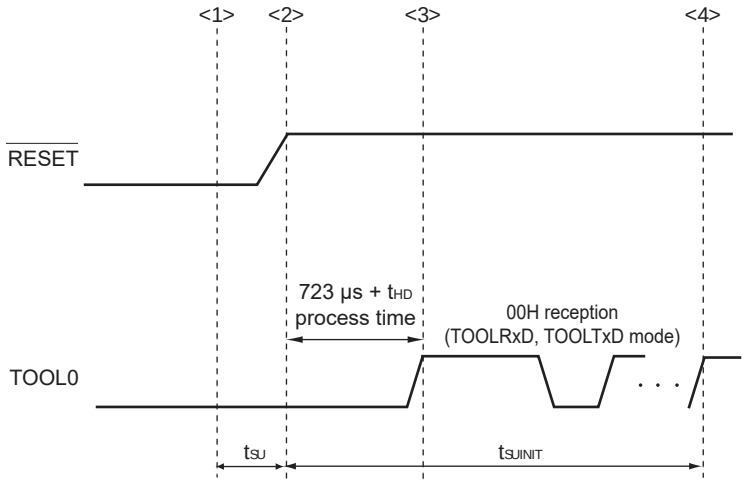
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During flash memory programming	115.2 k		1 M	bps

2.10 Timing Specs for Switching Flash Memory Programming Modes

(T_A = –40 to +85°C, 1.8 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	t_{SUINIT}	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until a external reset ends	t_{SU}	POR and LVD reset must end before the external reset ends.	10			μs
<R> How long the TOOL0 pin must be kept at the low level after an external reset ends (except flash firmware processing time)	t_{HD}	POR and LVD reset must end before the external reset ends.	1			ms

<R>



<1> The low level is input to the TOOL0 pin.
<2> The pins reset ends (POR and LVD reset must end before the external reset ends.).
<3> The TOOL0 pin is set to the high level.
<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark t_{SUINIT}: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

t_{SU}: How long from when the TOOL0 pin is placed at the low level until a external reset ends

<R> t_{HD}: How long to keep the TOOL0 pin at the low level from when the external resets end (except flash firmware processing time)

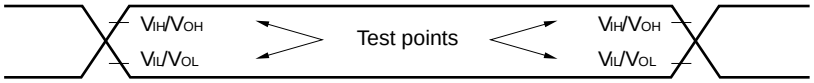
(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V) **(3/3)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I_{FIL} Note 1				0.20		μA
RTC operating current	I_{RTC} Notes 1, 2, 3				0.02		μA
12-bit interval timer operating current	I_{IT} Notes 1, 2, 4				0.02		μA
Watchdog timer operating current	I_{WDT} Notes 1, 2, 5	f_{IL} = 15 kHz			0.22		μA
A/D converter operating current	I_{ADC} Notes 6, 7	AV_{DD} = 3.0 V, When conversion at maximum speed			420	720	μA
$AV_{REF(+)}$ current	I_{AVREF} Note 8	AV_{DD} = 3.0 V, ADREFP1 = 0, ADREFP0 = 0 Note 7			14.0	25.0	μA
		AV_{REFP} = 3.0 V, ADREFP1 = 0, ADREFP0 = 1 Note 10			14.0	25.0	μA
		ADREFP1 = 1, ADREFP0 = 0 Note 1			14.0	25.0	μA
A/D converter reference voltage current	I_{ADREF} Notes 1, 9	V_{DD} = 3.0 V			75.0		μA
Temperature sensor operating current	I_{TMPS} Note 1	V_{DD} = 3.0 V			75.0		μA
LVD operating current	I_{LVD} Notes 1, 11				0.08		μA
BGO operating current	I_{BGO} Notes 1, 12				2.5	12.2	mA
Self-programming operating current	I_{FSP} Notes 1, 13				2.5	12.2	mA
SNOOZE operating current	I_{SNOZ}	A/D converter operation (AV_{DD} = 3.0 V)	The mode is performed Notes 1, 14		0.50	1.10	mA
			During A/D conversion Note 1		0.60	1.34	mA
			During A/D conversion Note 7		420	720	μA
		CSI/UART operation Note 1			0.70	1.54	mA

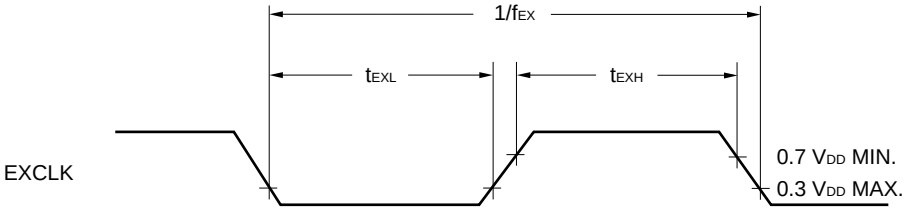
(**Notes** and **Remarks** are listed on the next page.)

AC Timing Test Points

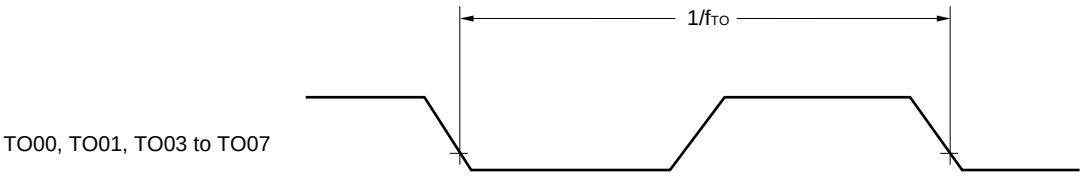
<R>



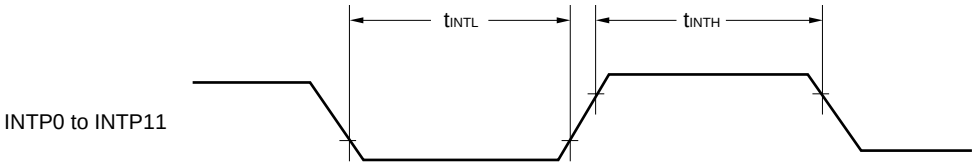
External System Clock Timing



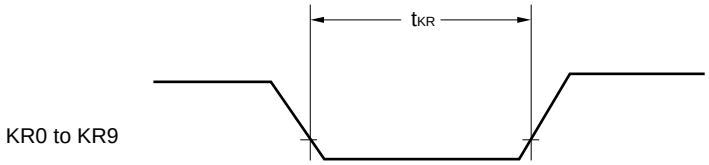
<R> TI/TO Timing



Interrupt Request Input Timing



Key Interrupt Input Timing



(7) Communication at different potential (1.8 V, 2.5 V) (CSI mode) (slave mode, SCKp... external clock input)
(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
SCKp cycle time[Note 1]	t_{KCY2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V	24 MHz < f_{MCK}	40/f_{MCK}			ns
			20 MHz < f_{MCK} ≤ 24 MHz	32/f_{MCK}			ns
			16 MHz < f_{MCK} ≤ 20 MHz	28/f_{MCK}			ns
			8 MHz < f_{MCK} ≤ 16 MHz	24/f_{MCK}			ns
			4 MHz < f_{MCK} ≤ 8 MHz	16/f_{MCK}			ns
			f_{MCK} ≤ 4 MHz	12/f_{MCK}			ns
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V	24 MHz < f_{MCK}	96/f_{MCK}			ns
			20 MHz < f_{MCK} ≤ 24 MHz	72/f_{MCK}			ns
			16 MHz < f_{MCK} ≤ 20 MHz	64/f_{MCK}			ns
			8 MHz < f_{MCK} ≤ 16 MHz	52/f_{MCK}			ns
			4 MHz < f_{MCK} ≤ 8 MHz	32/f_{MCK}			ns
			f_{MCK} ≤ 4 MHz	20/f_{MCK}			ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V		t_{KCY2}/2 – 36			ns
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		t_{KCY2}/2 – 100			ns
SIp setup time (to SCKp↑)[Note 2]	t_{SIK2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V		1/f_{MCK} + 40			ns
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		1/f_{MCK} + 60			
SIp hold time (from SCKp↑)[Note 2]	t_{KSI2}			1/f_{MCK} + 62			ns
Delay time from SCKp↓ to SOp output[Note 3]	t_{KSO2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ				2/f_{MCK} + 428	ns
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ				2/f_{MCK} + 1146	ns

Notes 1. Transfer rate in the SNOOZE mode : MAX. 1 Mbps

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time or SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

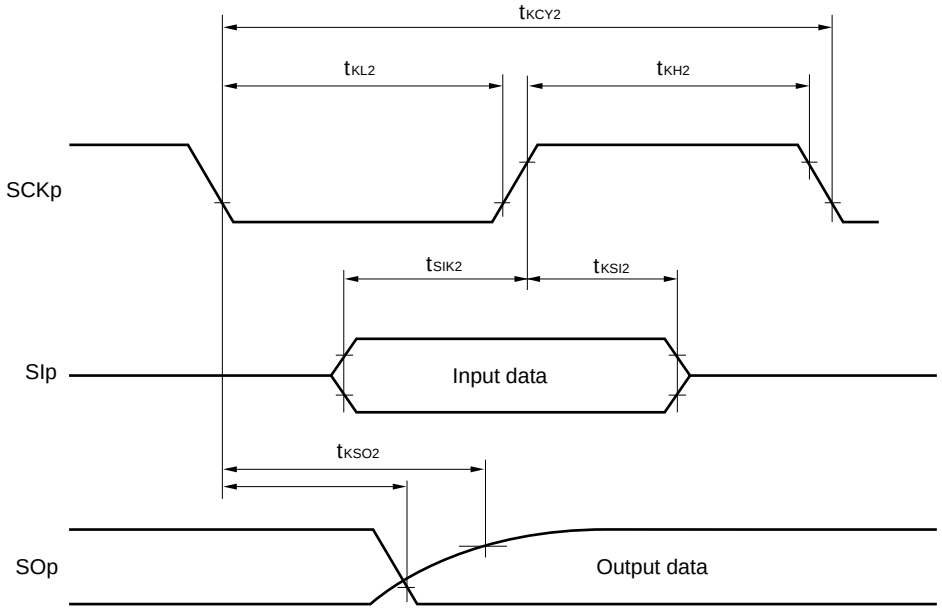
3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp pin and SCKp pin and the N-ch open drain output (V_{DD} tolerance (When 25- to 48-pin products)/EV_{DD} tolerance (When 64-pin products)) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

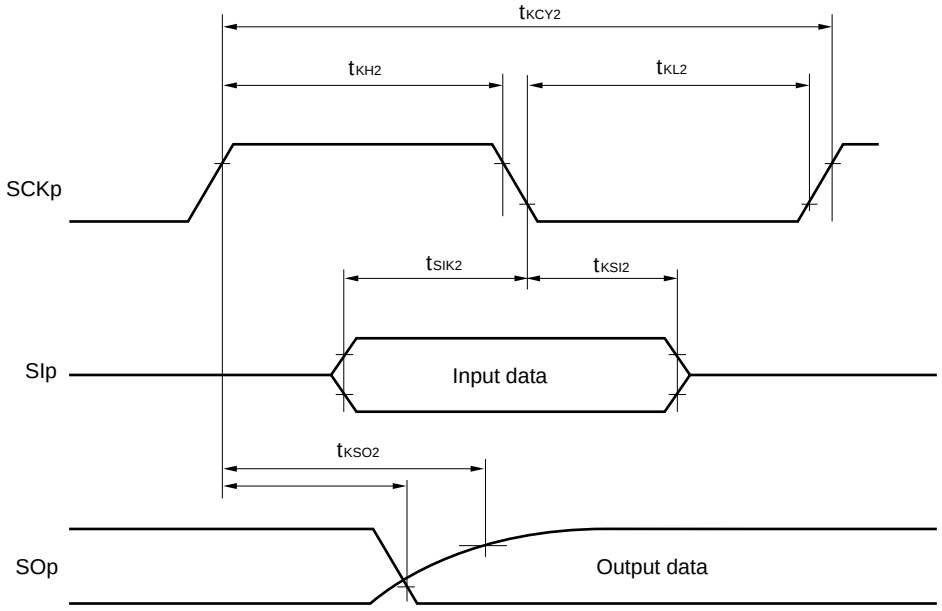
<R>

(**Remarks** are listed on the next page.)

CSI mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remarks 1. p: CSI number (p = 00, 10, 20), m: Unit number, n: Channel number (mn = 00, 02, 10), g: PIM and POM number (g = 0, 1)

2. CSI01, CSI11, and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

3.9 Dedicated Flash Memory Programmer Communication (UART)

(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

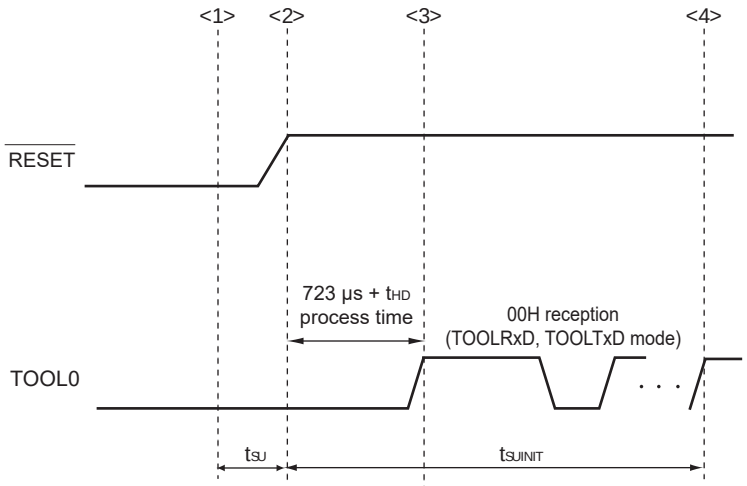
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During flash memory programming	115.2 k		1 M	bps

3.10 Timing Specs for Switching Flash Memory Programming Modes

(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	t_{SUINIT}	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until a external reset ends	t_{SU}	POR and LVD reset must end before the external reset ends.	10			μs
<R> How long the TOOL0 pin must be kept at the low level after an external reset ends (except flash firmware processing time)	t_{HD}	POR and LVD reset must end before the external reset ends.	1			ms

<R>



<1> The low level is input to the TOOL0 pin.
<2> The pins reset ends (POR and LVD reset must end before the external reset ends.).
<3> The TOOL0 pin is set to the high level.
<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark t_{SUINIT}: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

t_{SU}: How long from when the TOOL0 pin is placed at the low level until a external reset ends

<R> t_{HD}: How long to keep the TOOL0 pin at the low level from when the external resets end (except flash firmware processing time)

Rev.	Date	Description	
		Page	Summary
2.10	Nov 30, 2016	p.73	Modification of 2.10 Timing Specs for Switching Flash Memory Programming Modes
		p.77	Modification of 3.2.1 X1, XT1 oscillator characteristics
		p.78, 79	Modification of 3.3.1 Pin characteristics
		p.88	Modification of 3.3.2 Supply current characteristics
		p.90	Modification of Minimum Instruction Execution Time during Main System Clock Operation
		p.91	Modification of AC Timing Test Points and TI/TO Timing
		p.93	Modification of AC Timing Test Points in 3.5 Peripheral Functions Characteristics
		p.95	Modification of 3.5.1 Serial array unit
		p.99, 100, 102, 103, 105, 109	Modification of Caution in 2.5.1 Serial array unit
		p.112 to 116	Modification of 3.6.1 (1) to (5)
		p.118	Renamed to 3.7 RAM Data Retention Characteristics, and modification of note and figure
		p.118	Addition of note 4 to 3.8 Flash Memory Programming Characteristics
		p.119	Modification of 3.10 Timing Specs for Switching Flash Memory Programming Modes
		p.120	Modification of 4.1 25-pin products
		p.123	Modification of 4.3 48-pin products